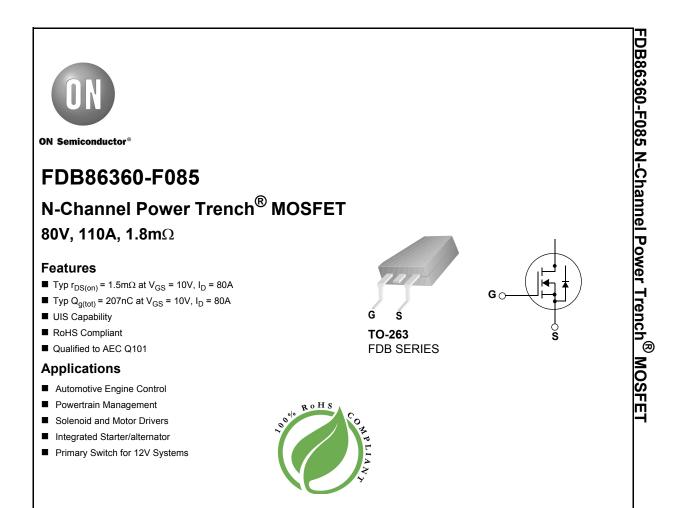
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MOSFET Maximum Ratings T_J = 25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain to Source Voltage		80	V
V _{GS}	Gate to Source Voltage		±20	V
	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	110	۸
D	Pulsed Drain Current	T _C = 25°C	See Figure4	A
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	1167	mJ
	Power Dissipation		333	W
PD	Derate above 25°C		2.22	W/ºC
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C
$R_{ ext{ heta}JC}$	Thermal Resistance Junction to Case		0.45	°C/W
R _{0JA}	Maximum Thermal Resistance Junction to Ambient	(Note 3)	43	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB86360	FDB86360-F085	D2-PAK(TO-263)	330mm	24mm	800 units

Notes:

1: Current is limited by bondwire configuration. 2: Starting $T_J = 25^{\circ}C$, L = 0.57mH, I_{AS} = 64A, V_{DD} = 80V during inductor charging and V_{DD} = 0V during time in avalanche 3: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Cha	racteristics					
B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V	80	-	-	V
 	Drain to Source Leakage Current	V_{DS} =80V, T_{J} =25°C	-	-	1	μA
DSS	Drain to Source Leakage Current	$V_{GS} = 0V$ $T_J = 175^{\circ}C(Not$	e 4) -	-	1	mA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$	-	-	±100	nA
DS(on)	Drain to Source On Resistance			-	-	
r _{DS(on)}	Drain to Source On Resistance	$I_D = 80A,$ $T_J = 25^{\circ}C$ $V_{GS} = 10V$ $T_J = 175^{\circ}C(Not)$	- e 4) -	1.5 2.7	1.8 3.2	mΩ mΩ
		19=113 0(100	- (-	2.1	0.2	1115.2
Dynami	c Characteristics					
C _{iss}	Input Capacitance			14600	-	pF
C _{oss}	Output Capacitance	─V _{DS} = 25V, V _{GS} = 0V, f = 1MHz	-	4700	-	pF
C _{rss}	Reverse Transfer Capacitance		-	370	-	pF
R _g	Gate Resistance	f = 1MHz		3.2	-	Ω
	Total Gate Charge at 10V	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 40^{\circ}$	v -	207	253	nC
Q _{g(ToT)}	ů,				-	-
Q _{g(ToT)} Q _{g(th)}	Threshold Gate Charge	$V_{GS} = 0 \text{ to } 2V$ $I_D = 80A$	-	27	34	nC
Q _{g(ToT)} Q _{g(th)} Q _{gs}	Threshold Gate Charge Gate to Source Gate Charge	$V_{GS} = 0 \text{ to } 2V$ $I_D = 80A$		27 78	34 -	nC nC

Switching Characteristics

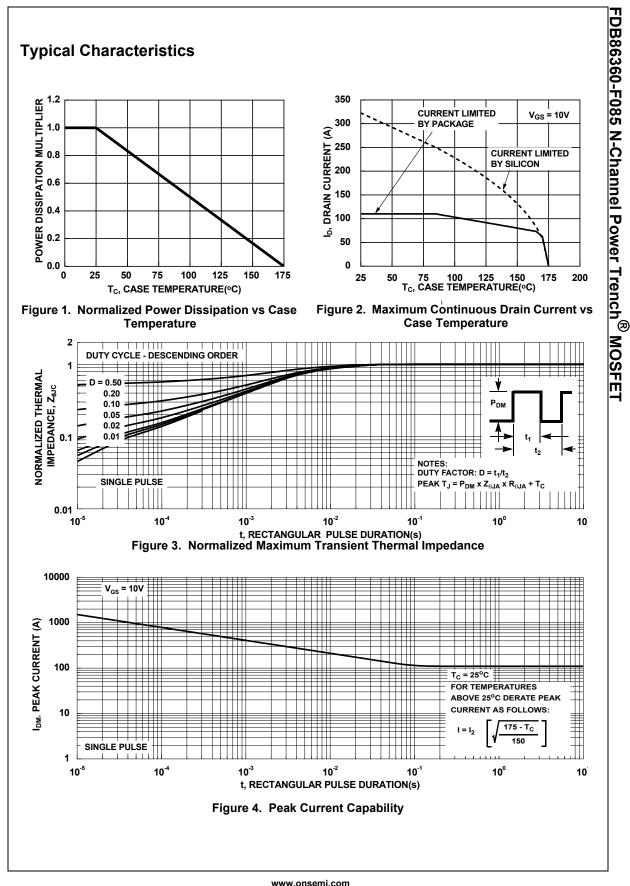
t _{on}	Turn-On Time		-	-	388	ns
t _{d(on)}	Turn-On Delay Time		-	75	-	ns
t _r	Rise Time	V _{DD} = 40V, I _D = 80A,	-	197	-	ns
t _{d(off)}	Turn-Off Delay Time	V_{DD} = 40V, I _D = 80A, V _{GS} = 10V, R _{GEN} = 6Ω	-	86	-	ns
t _f	Fall Time		-	70	-	ns
t _{off}	Turn-Off Time		-	-	226	ns

Drain-Source Diode Characteristics

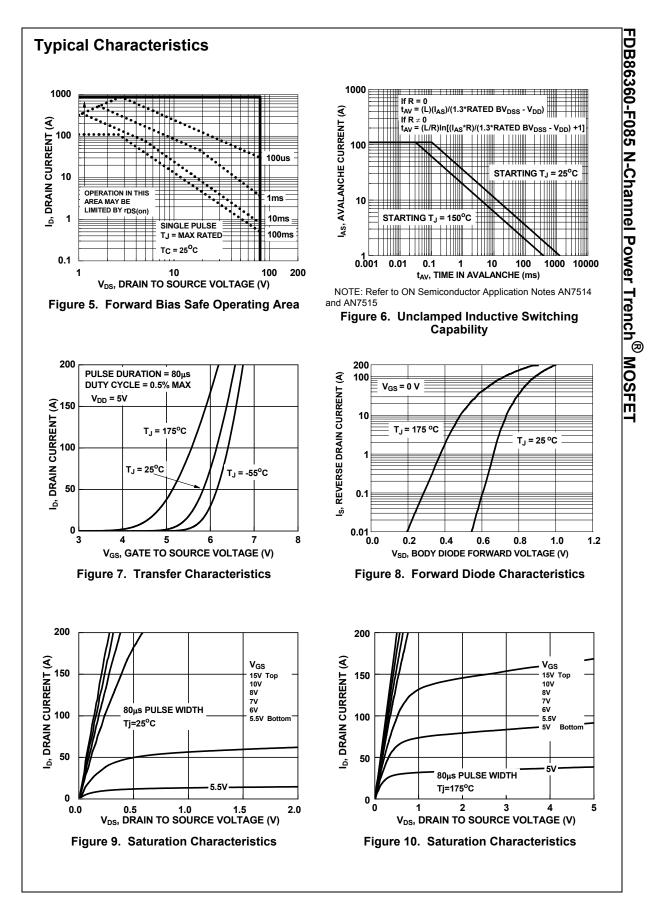
Var	Source to Drain Diode Voltage	I _{SD} = 80A, V _{GS} = 0V	-	-	1.25	V
V _{SD}	Source to Drain Diode Voltage	I _{SD} = 40A, V _{GS} = 0V	-	-	1.2	V
T _{rr}	Reverse Recovery Time	I _F = 80A, dI _{SD} /dt = 100A/μs,	-	103	120	ns
Q _{rr}	Reverse Recovery Charge	V _{DD} =64V	-	212	260	nC

Notes:

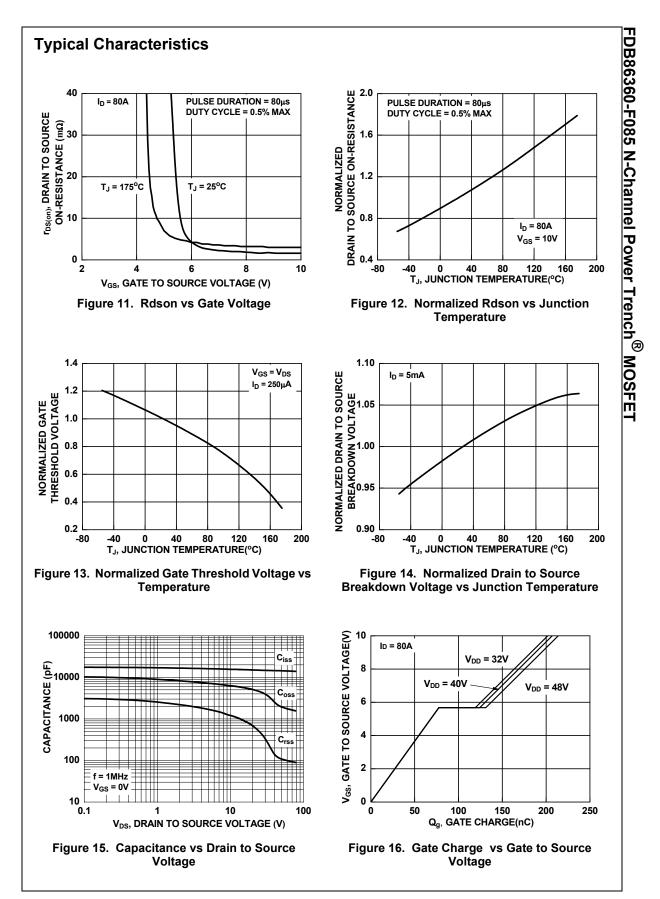
4: The maximum value is specified by design at T_J = 175°C. Product is not tested to this condition in production.



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